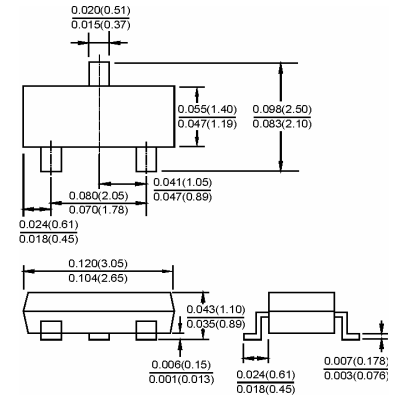




1. BASE
2. EMITTER
3. COLLECTOR

## SOT-23



Dimensions in inches and (millimeters)

## Features

- ✧ Darlingon Amplifier

Marking : MMBTA13:K2D; MMBTA14:K3D

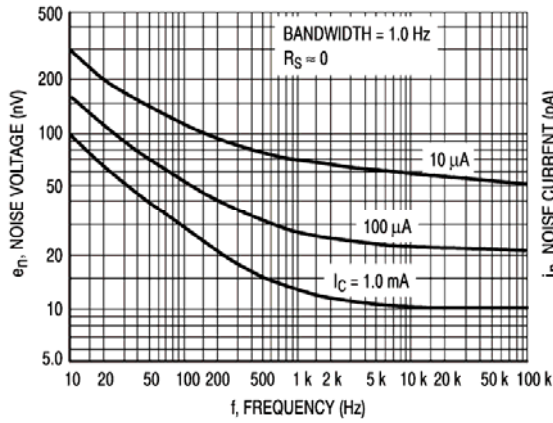
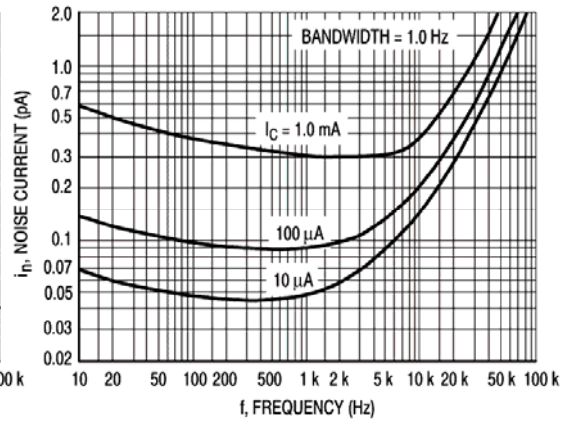
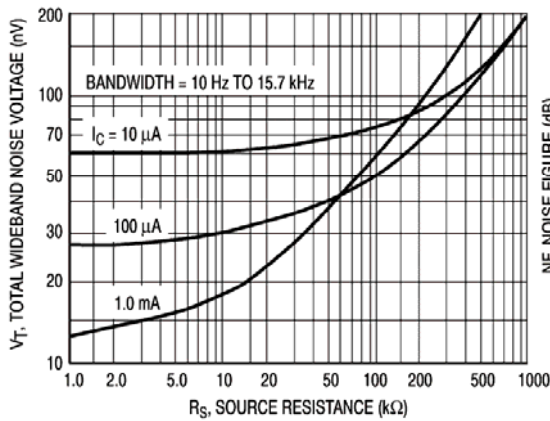
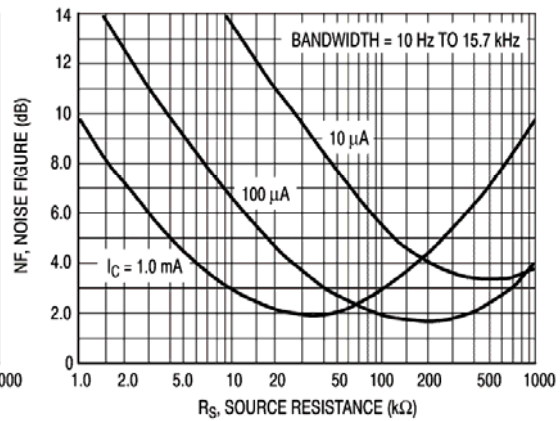
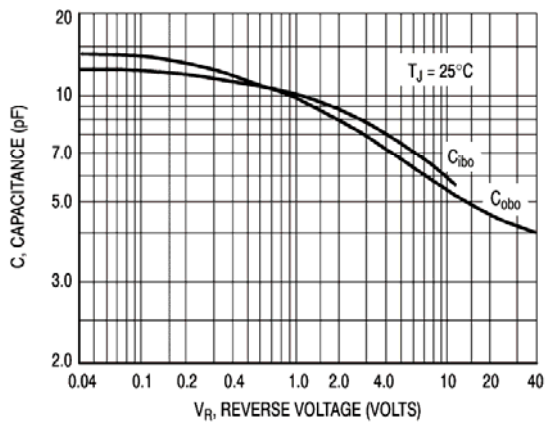
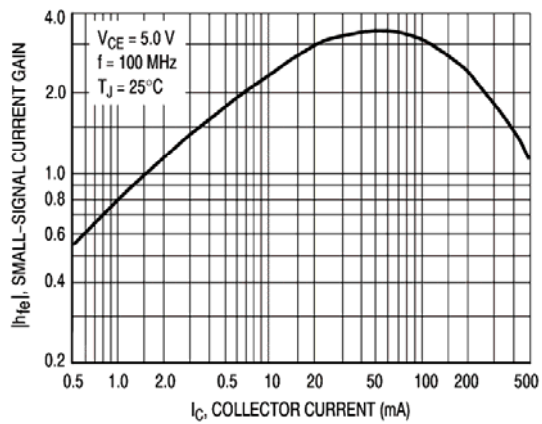
## MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Units
V <sub>CB0</sub>	Collector-Base Voltage	30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
I <sub>C</sub>	Collector Current -Continuous	0.3	A
P <sub>C</sub>	Collector Power Dissipation	350	mW
R <sub>θJA</sub>	Thermal Resistance Junction to Ambient	417	°C/W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55 to +150	°C

## ELECTRICAL CHARACTERISTICS (T<sub>amb</sub>=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 100μA, I <sub>E</sub> =0	30		V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 100uA, I <sub>B</sub> =0	30		V
Collector-emitter breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 100μA, I <sub>C</sub> =0	10		V
Collector cut-off current	I <sub>CBO</sub> *	V <sub>CB</sub> =30 V, I <sub>E</sub> =0		0.1	μA
Emitter cut-off current	I <sub>EBO</sub> *	V <sub>EB</sub> = 10V, I <sub>C</sub> =0		0.1	μA
DC current gain	h <sub>FE(1)</sub> *	V <sub>CE</sub> =5V, I <sub>C</sub> = 10mA	MMBTA13	5000	
	h <sub>FE(2)</sub> *	V <sub>CE</sub> =5V, I <sub>C</sub> = 100mA	MMBTA13	10000	
			MMBTA14	20000	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *	I <sub>C</sub> =100mA, I <sub>B</sub> =0.1mA		1.5	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub> *	I <sub>C</sub> =100mA, I <sub>B</sub> =0.1mA		2	V
Base-emitter voltage	V <sub>BE</sub> *	V <sub>CE</sub> =5V, I <sub>C</sub> = 100mA		2.0	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> = 10mA f=100MHz	125		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		12	pF

\* Pulse Test : pulse width≤300μs, duty cycle≤2%.

**Typical Characteristics**

**Figure 2. Noise Voltage**

**Figure 3. Noise Current**

**Figure 4. Total Wideband Noise Voltage**

**Figure 5. Wideband Noise Figure**

**Figure 6. Capacitance**

**Figure 7. High Frequency Current Gain**

### Typical Characteristics

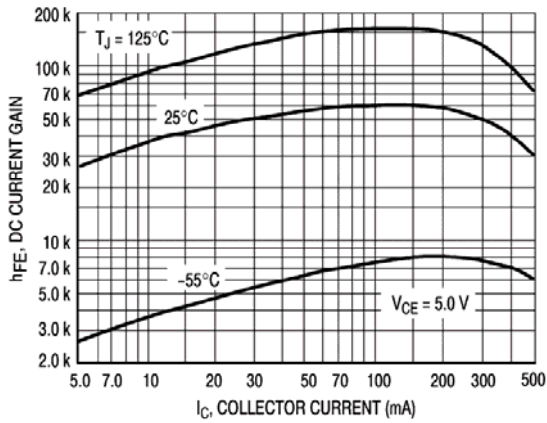


Figure 8. DC Current Gain

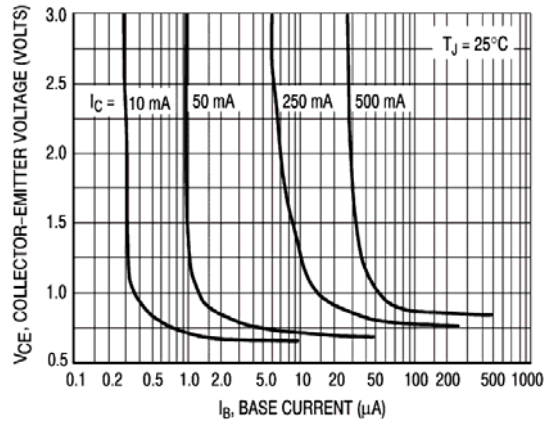


Figure 9. Collector Saturation Region

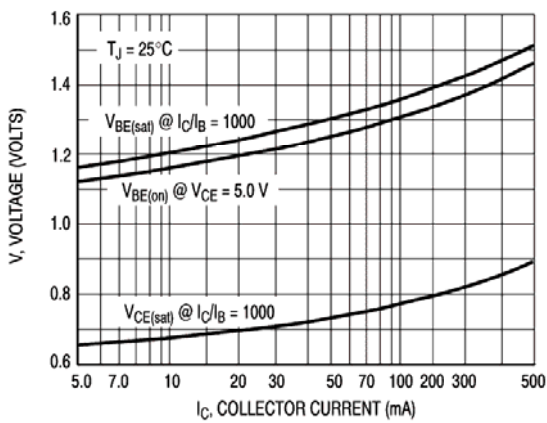


Figure 10. "On" Voltages

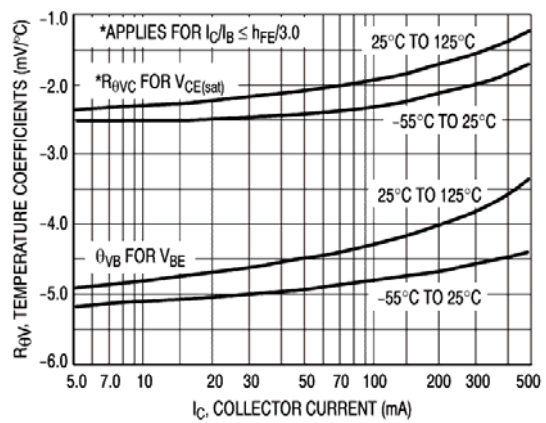


Figure 11. Temperature Coefficients

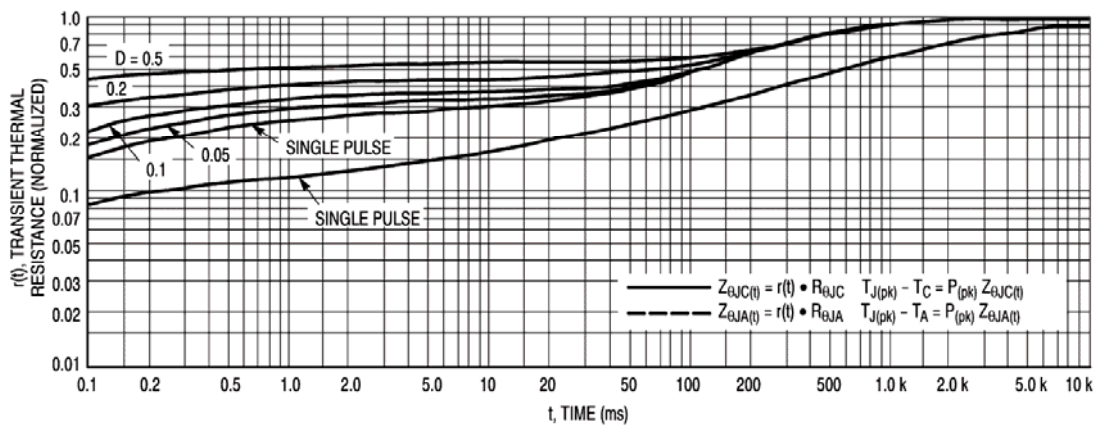


Figure 12. Thermal Response